

FDMC0310AS

Data Sheet

Trans MOSFET N-CH 30V 19A 8-Pin WDFN EP T/R

Manufacturers ON Semiconductor, LLC

Package/Case QFN-8

Product Type Transistors

RoHS Green

Lifecycle



Images are for reference only

Please submit RFQ for FDMC0310AS or Email to us: sales@ovaga.com We will contact you in 12 hours.



General Description

The FDMC0310AS has been designed to minimize losses in power conversion application. Advancements in both silicon and package technologies have been combined to offer the lowest rDS(on) while maintaining excellent switching performance. This device has the added benefit of an efficient monolithic schottky body diode.

Features Application

Max. = 10 V,>

Max. = 4.5 V,>

Advanced package and silicon combination for low rDS(on) and high efficiency

SyncFETTM Schottky Body Diode

MSL1 robust package design

100% UIL tested

RoHS Compliant



Related Products



FDC645N

ON Semiconductor, LLC SSOT-6



FDC6305N

ON Semiconductor, LLC SSOT-6



FDD8647L

ON Semiconductor, LLC TO-252-3



FDD5N50NZTM

ON Semiconductor, LLC TO-252



FDC637BNZ

ON Semiconductor, LLC SSOT-6



FDC602P

ON Semiconductor, LLC SOT163



FDB070AN06A0

ON Semiconductor, LLC TO-263



FDD3670

ON Semiconductor, LLC TO-252AA